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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/817,469	04/02/2004	Manfred Dobler	INF 2283-US	3189	
46798 7	590 07/25/2005		EXAMINER		
MOSER, PATTERSON & SHERIDAN, LLP			HOANG, HUAN		
	CLELLAN/INFINEON		ART UNIT	PAPER NUMBER	
3040 POST OA SUITE 1500	AK BLVD.,		2827		
HOUSTON, T	HOUSTON, TX 77056			DATE MAILED: 07/25/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

			XK
	Application No.	Applicant(s)	<u>.</u>
	10/817,469	DOBLER, MANE	FRED
Office Action Summary	Examiner	Art Unit	
	Huan Hoang	2827	
The MAILING DATE of this communication a Period for Reply	ppears on the cover	sheet with the correspondence a	address
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a r - If NO period for reply is specified above, the maximum statutory perions - Failure to reply within the set or extended period for reply will, by state than the period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than the period for reply will be supported by the Office later than the period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for reply will be supported by the Office later than three months after the man period for repl	N. 1.136(a). In no event, howeveply within the statutory mining will apply and will expire State, cause the application to	er, may a reply be timely filed num of thirty (30) days will be considered tim X (6) MONTHS from the mailing date of this become ABANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on			
• • • • • • • • • • • • • • • • • • • •	—— nis action is non-final		
3) Since this application is in condition for allow closed in accordance with the practice unde	·	·	he merits is
Disposition of Claims			
4) ☐ Claim(s) 1-19 is/are pending in the application 4a) Of the above claim(s) is/are withd 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-4,6,7,10-14 and 16-18 is/are rejee 7) ☐ Claim(s) 5,8,9,15 and 19 is/are objected to. 8) ☐ Claim(s) are subject to restriction and	rawn from considera cted.		
Application Papers			
9)☐ The specification is objected to by the Exami	ner.		
10)☐ The drawing(s) filed on is/are: a)☐ a	ccepted or b)□ obje	cted to by the Examiner.	
Applicant may not request that any objection to the	• • • • • • • • • • • • • • • • • • • •	•	
Replacement drawing sheet(s) including the corr 11) The oath or declaration is objected to by the	•		
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for forei a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a light	ents have been receivents have been receivents have been receivents have been receivents have au (PCT Rule 17.2)	ved. ved in Application No ve been received in this National a)).	al Stage
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		nterview Summary (PTO-413) aper No(s)/Mail Date	
 Notice of Drattsperson's Patent Drawing Review (PTO-946) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/I Paper No(s)/Mail Date <u>040204</u>. 	08) 5) 🔲 🗅	Notice of Informal Patent Application (P	TO-152)

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DETAILED ACTION

Information Disclosure Statement

1. The Non Patent Literature Document C2 of the information disclosure statement filed 04/02/04 fails to comply with 37 CFR 1.98(a)(3) because it does not include a concise explanation of the relevance, as it is presently understood by the individual designated in 37 CFR 1.56(c) most knowledgeable about the content of the information, of each patent listed that is not in the English language. It has been placed in the application file, but the information referred to therein has not been considered.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.
- 3. Claims 1-4, 6, 7, 10-14, 16, 17 and 18 are rejected under 35 U.S.C. 102(a) as being anticipated by Tsubouchi et al..

Tsubouchi et al. discloses a method of refreshing a dynamic memory cell in a memory circuit and a memory circuit having all the steps and elements as recited in claims 1-4, 6, 7, 10-14, 16, 17 and 18 as follows:

during read-out of the memory cell, activating the word line (Fig. 9) and separating a charge difference brought about thereby on the bit line s into a high charge potential and a low charge potential (Fig. 9, READ OPERATION);

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after the read out, charging the potential of the bit lines to a first center potential (Fig. 9, READ OPERATION);

during refresh of the memory cell, activating the word line and separating the charge potentials of the bit lines, depending on the charge information of the memory cell, in the direction of a high refresh potential and a low refresh potential (Fig. 9, REFRESH OPERATION);

after the refresh, charging the potentials of the bit lines to a second center potential, wherein the potential difference between the high refresh potential and the second center potential is greater than the potential difference between the high charge potential and the first center potential ($\Delta V1 > \Delta V0$, paragraph [0148], lines 6-10)

a refresh circuit (74, 76, 80 and 82, Fig. 3);

a charge equalization circuit (Fig. 6);

a sense amplifier (SAK, Fig. 6); and

voltage control means (sense amplifier and charge equalization circuit).

Allowable Subject Matter

4. Claims 5, 8, 9, 15 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

The prior art does not teach the following:

wherein the first center potential is greater than the second center potential.

wherein a time duration of the refresh period after which the memory cell is

periodically refreshed is increased after a first refresh following a write or read access to

the memory cell.

third and fourth potential sources wherein the third potential source is lower than the fourth potential source.

Conclusion

5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Hamamoto discloses a semiconductor memory device.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Huan Hoang whose telephone number is (571) 272-1779. The examiner can normally be reached on Mon-Fri 8:30AM-5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoai Ho can be reached on (571) 272-1777. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Primary Examiner

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HH 7/20/05.